

TLV6703-Q1 Automotive Micropower, 18-V Comparator With 400-mV Reference

1 Features

- Qualified for automotive applications
- AEC-Q100 qualified with the following results:
 - Device temperature grade 1: -40°C to $+125^{\circ}\text{C}$ ambient operating temperature range
 - Device HBM ESD classification level H2
 - Device CDM ESD classification level C6
- Wide supply voltage range: 1.8 V to 18 V
- Adjustable threshold: down to 400 mV
- High threshold accuracy:
 - 0.5% Max at 25°C
 - 1.0% Max over temperature
- Low quiescent current: 5.5 μA (Typ)
- Open-drain output
- Internal hysteresis: 5.5 mV (Typ)
- Temperature range: -40°C to $+125^{\circ}\text{C}$
- Package: leadless WSON-6

2 Applications

- [Emergency call \(eCall\)](#)
- [Automotive head unit](#)
- [Instrument cluster](#)
- [On-board \(OBC\) & wireless charger](#)

3 Description

The TLV6703-Q1 high voltage comparator operates over a 1.8-V to 18-V range. The TLV6703-Q1 has a high-accuracy comparator with an internal 400-mV reference and an open-drain output rated to 18 V for precision voltage detection. The monitored voltage can be set with the use of external resistors.

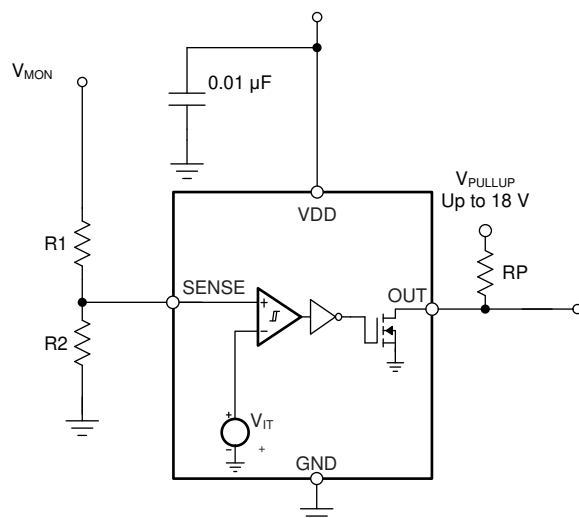
The OUT pin is driven low when the voltage at the SENSE pin drops below (V_{IT-}), and goes high when the voltage returns above the respective threshold (V_{IT+}). The comparator in the TLV6703-Q1 includes built-in hysteresis for filtering to reject brief glitches, thereby ensuring stable output operation without false triggering.

The TLV6703-Q1 is available in a leadless WSON-6 package and is specified over the junction temperature range of -40°C to $+125^{\circ}\text{C}$.

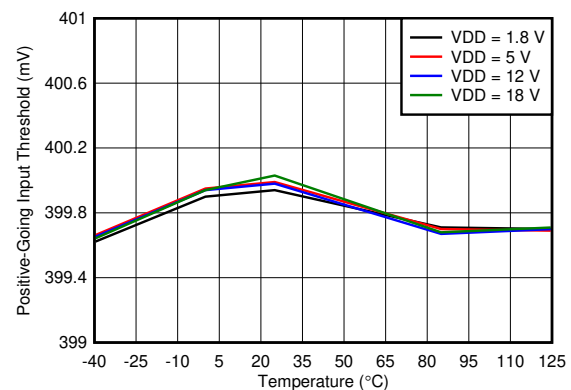
Device Information (1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TLV6703-Q1	WSON (6)	1.50 mm $\times$ 1.50 mm

- (1) For all available packages, see the package option addendum at the end of the datasheet.



Simplified Block Diagram



Rising Input Threshold Voltage (V_{IT+}) vs Temperature



Table of Contents

1 Features	1	8.3 Feature Description.....	11
2 Applications	1	8.4 Device Functional Modes.....	11
3 Description	1	9 Application and Implementation	12
4 Revision History	2	9.1 Application Information.....	12
5 Device Comparison Table	3	9.2 Typical Application.....	14
6 Pin Configuration and Functions	4	9.3 Dos and Don'ts.....	15
7 Specifications	5	10 Power-Supply Recommendations	16
7.1 Absolute Maximum Ratings.....	5	11 Layout	17
7.2 ESD Ratings.....	5	11.1 Layout Guidelines.....	17
7.3 Recommended Operating Conditions.....	5	11.2 Layout Example.....	17
7.4 Thermal Information.....	5	12 Device and Documentation Support	18
7.5 Electrical Characteristics.....	6	12.1 Device Support.....	18
7.6 Timing Requirements.....	7	12.2 Receiving Notification of Documentation Updates..	18
7.7 Switching Characteristics.....	7	12.3 Support Resources.....	18
7.8 Timing Diagrams	7	12.4 Trademarks.....	18
7.9 Typical Characteristics.....	8	12.5 Electrostatic Discharge Caution.....	18
8 Detailed Description	10	12.6 Glossary.....	18
8.1 Overview.....	10	13 Mechanical, Packaging, and Orderable Information	18
8.2 Functional Block Diagram.....	10		

4 Revision History

DATE	REVISION	NOTES
November 2020	*	Initial release.

5 Device Comparison Table

Table 5-1. TLV67xx Integrated Comparator Family

PART NUMBER	CONFIGURATION	OPERATING VOLTAGE RANGE	THRESHOLD ACCURACY OVER TEMPERATURE
TLV6700	Window	1.8 V to 18 V	1%
TLV6700-Q1	Window	1.8 V to 18 V	1%
TLV6703	Non-Inverting Single Channel	1.8 V to 18 V	1%
TLV6703-Q1	Non-Inverting Single Channel	1.8 V to 18 V	1%
TLV6710	Window	1.8 V to 36 V	0.75%
TLV6713	Non-Inverting Single Channel	1.8 V to 36 V	0.75%

6 Pin Configuration and Functions

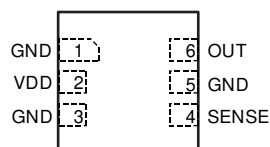


Figure 6-1. DSE Package, 6-Pin WSON, Top View

Table 6-1. Pin Functions

PIN		I/O	DESCRIPTION
NAME	DSE		
GND	1,3,5	—	Connect all three pins to ground.
OUT	6	O	SENSE comparator open-drain output. OUT is driven low when the voltage at this comparator is below (V_{IT-}). The output goes high when the sense voltage returns above the respective threshold (V_{IT+}).
SENSE	4	I	This pin is connected to the voltage to be monitored with the use of an external resistor divider. When the voltage at this pin drops below the threshold voltage (V_{IT-}), OUT is driven low.
VDD	2	I	Supply voltage input. Connect a 1.8-V to 18-V supply to VDD to power the device. Good analog design practice is to place a 0.1- μ F ceramic capacitor close to this pin.

7 Specifications

7.1 Absolute Maximum Ratings

over operating temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Voltage ⁽²⁾	VDD	−0.3	20	V
	OUT	−0.3	20	
	SENSE	−0.3	7	
Current	OUT (output sink current)		40	mA
Temperature	Operating junction, T _J	−40	125	°C
	Storage, T _{stg}	−65	150	

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to network ground pin.

7.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human body model (HBM), per AEC Q100-002, all pins ⁽¹⁾	±2500	V
	Charged device model (CDM), per AEC Q100-002, all pins	±1000	

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with ANSI/ESDA/JEDEC JS-001 specification.

7.3 Recommended Operating Conditions

over operating temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{DD}	Supply voltage	1.8		18	V
V _I	Input voltage	SENSE		6.5	V
V _O	Output voltage	OUT		18	V

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		DSE (WSON)	UNIT
		6 PADS	
R _{θJA}	Junction-to-ambient thermal resistance	194.9	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	128.9	°C/W
R _{θJB}	Junction-to-board thermal resistance	153.8	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	11.9	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	157.4	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor an IC Package Thermal Metrics](#) application report.

7.5 Electrical Characteristics

Over the operating temperature range of $T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, and $1.8\text{ V} < V_{DD} < 18\text{ V}$ (unless otherwise noted).

Typical values are at $T_J = 25^{\circ}\text{C}$ and $V_{DD} = 5\text{ V}$.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(POR)}$	Power-on reset voltage ⁽¹⁾	$V_{OLmax} = 0.2\text{ V}$, output sink current = $15\text{ }\mu\text{A}$			0.8	V
V_{IT+}	Positive-going input threshold voltage	$V_{DD} = 1.8\text{ V}$ and 18 V , $T_J = 25^{\circ}\text{C}$	398	400	402.5	mV
		$V_{DD} = 1.8\text{ V}$ and 18 V , $T_J = -40^{\circ}\text{C}$ to 125°C	396		404	
V_{IT-}	Negative-going input threshold voltage	$V_{DD} = 1.8\text{ V}$ and 18 V , $T_J = 25^{\circ}\text{C}$	391.6	394.5	397.5	mV
		$V_{DD} = 1.8\text{ V}$ and 18 V , $T_J = -40^{\circ}\text{C}$ to 125°C	387		400	
V_{hys}	Hysteresis voltage ($hys = V_{IT+} - V_{IT-}$)			5.5	12	mV
$I_{(SENSE)}$	Input current (at the SENSE pin)	$V_{DD} = 1.8\text{ V}$ and 18 V , $V_I = 6.5\text{ V}$	-25	1	25	nA
V_{OL}	Low-level output voltage	$V_{DD} = 1.8\text{ V}$, output sink current = 3 mA			250	mV
		$V_{DD} = 5\text{ V}$, output sink current = 5 mA			250	
$I_{lk(OD)}$	Open-drain output leakage-current	$V_{DD} = 1.8\text{ V}$ and 18 V , $V_O = V_{DD}$			300	nA
		$V_{DD} = 1.8\text{ V}$, $V_O = 18\text{ V}$			300	
I_{DD}	Supply current	$V_{DD} = 1.8\text{ V}$, no load		5.5	11	μA
		$V_{DD} = 5\text{ V}$		6	13	
		$V_{DD} = 12\text{ V}$		6	13	
		$V_{DD} = 18\text{ V}$		7	13	
UVLO	Undervoltage lockout ⁽²⁾	V_{DD} falling	1.3		1.7	V

(1) The lowest supply voltage (V_{DD}) at which output is active; $t_{r(VDD)} > 15\text{ }\mu\text{s/V}$. Below $V_{(POR)}$, the output cannot be determined.

(2) When V_{DD} falls below UVLO, OUT is driven low. The output cannot be determined below $V_{(POR)}$.

7.6 Timing Requirements

over operating temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
$t_{pd(HL)}$	High-to-low propagation delay ⁽¹⁾		18		μs
$t_{pd(LH)}$	Low-to-high propagation delay ⁽¹⁾		29		μs
$t_{d(start)}$	Start-up delay ⁽²⁾		150		μs

(1) High-to-low and low-to-high refers to the transition at the input pin (SENSE).

(2) During power on, V_{DD} must exceed 1.8 V for at least 150 μs before the output is in a correct state.

7.7 Switching Characteristics

over operating temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_r	Output rise time $V_{DD} = 5\text{ V}$, 10-mV input overdrive, $R_P = 10\text{ k}\Omega$, $V_O = (0.1\text{ to }0.9) \times V_{DD}$		2.2		μs
t_f	Output fall time $V_{DD} = 5\text{ V}$, 10-mV input overdrive, $R_P = 10\text{ k}\Omega$, $V_O = (0.1\text{ to }0.9) \times V_{DD}$		0.22		μs

7.8 Timing Diagrams

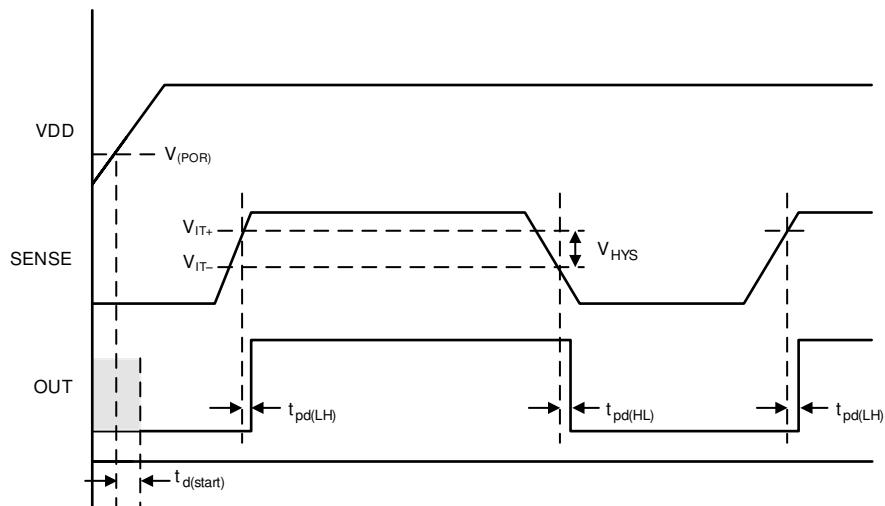


Figure 7-1. Timing Diagram

7.9 Typical Characteristics

at $T_J = 25^\circ\text{C}$ and $V_{DD} = 5\text{ V}$ (unless otherwise noted)

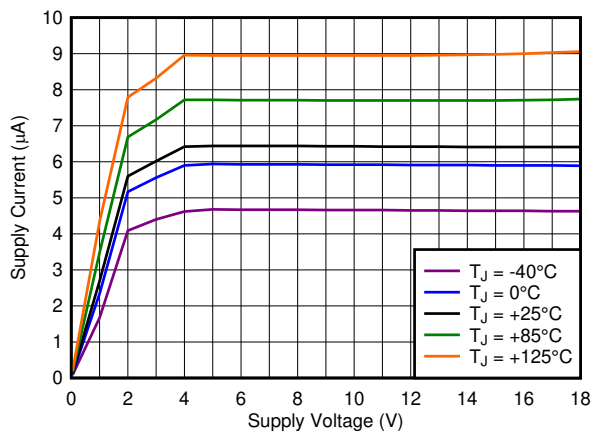


Figure 7-2. Supply Current (I_{DD}) vs Supply Voltage (V_{DD})

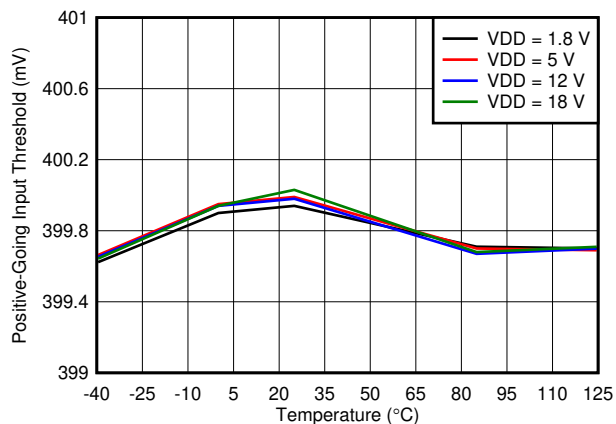


Figure 7-3. Rising Input Threshold Voltage (V_{IT+}) vs Temperature

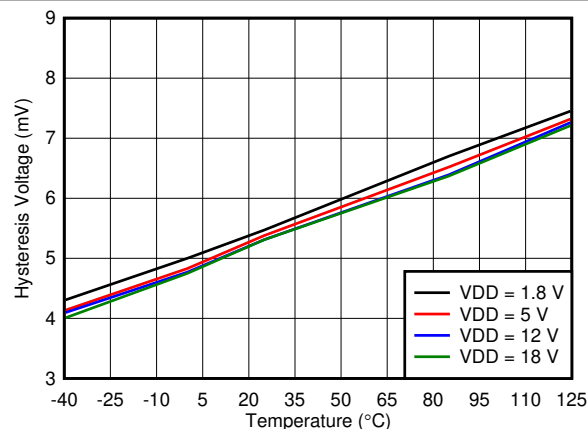


Figure 7-4. Hysteresis (V_{hys}) vs Temperature

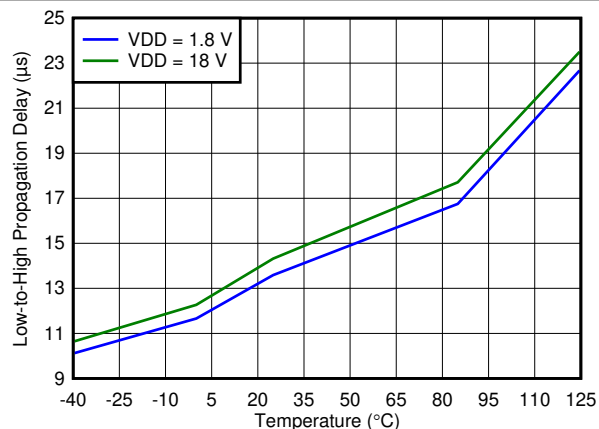


Figure 7-5. Propagation Delay vs Temperature (High-to-Low Transition at Sense)

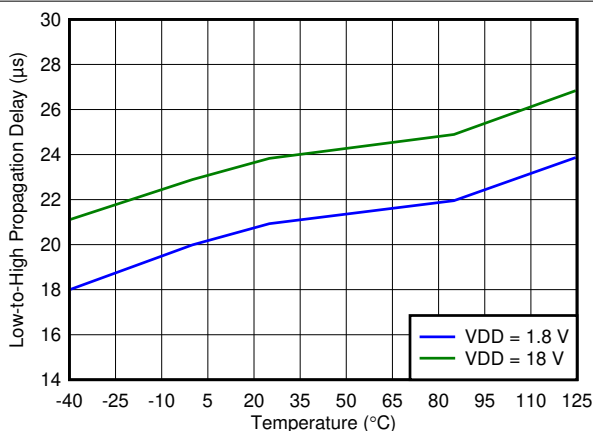


Figure 7-6. Propagation Delay vs Temperature (Low-to-High Transition at Sense)

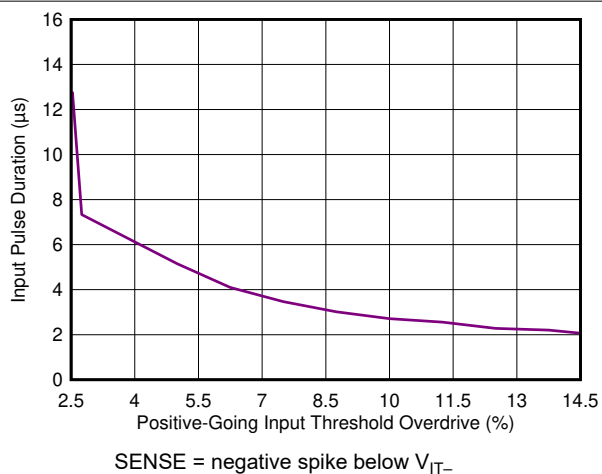


Figure 7-7. Minimum Pulse Width vs Threshold Overdrive Voltage

7.9 Typical Characteristics (continued)

at $T_J = 25^\circ\text{C}$ and $V_{DD} = 5\text{ V}$ (unless otherwise noted)

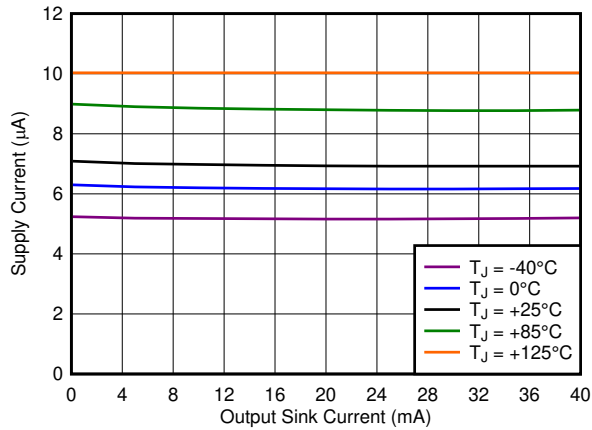


Figure 7-8. Supply Current (I_{DD}) vs Output Sink Current

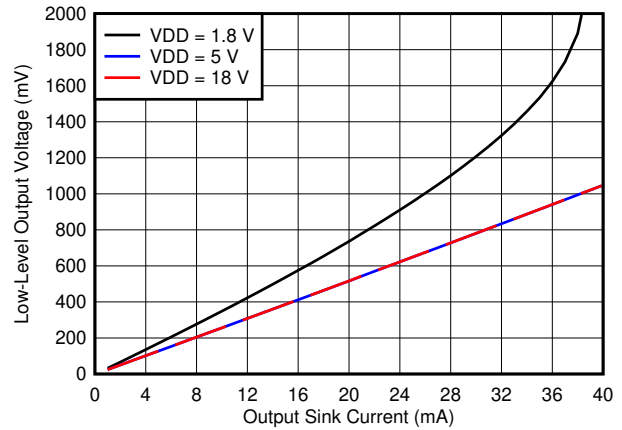


Figure 7-9. Output Voltage Low (V_{OL}) vs Output Sink Current (-40°C)

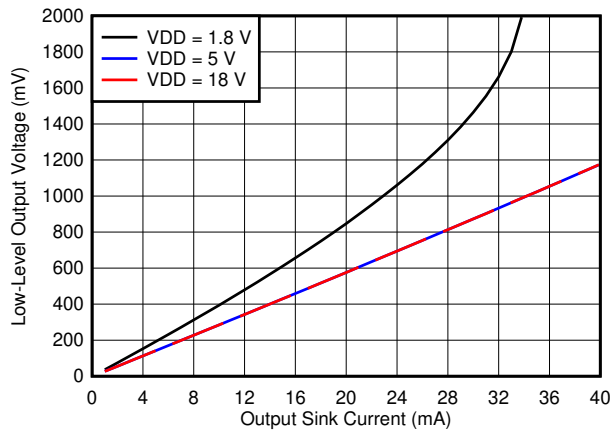


Figure 7-10. Output Voltage Low (V_{OL}) vs Output Sink Current (0°C)

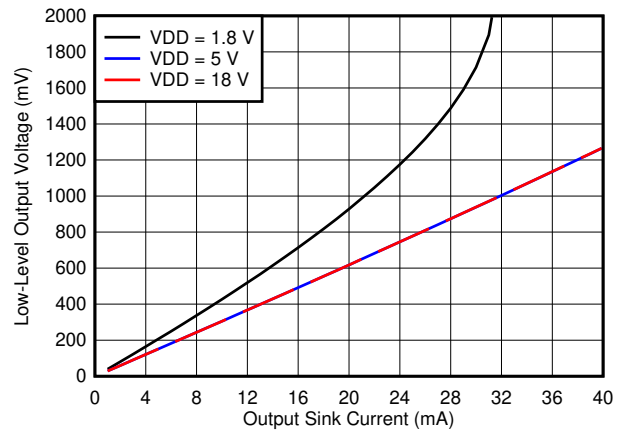


Figure 7-11. Output Voltage Low (V_{OL}) vs Output Sink Current (25°C)

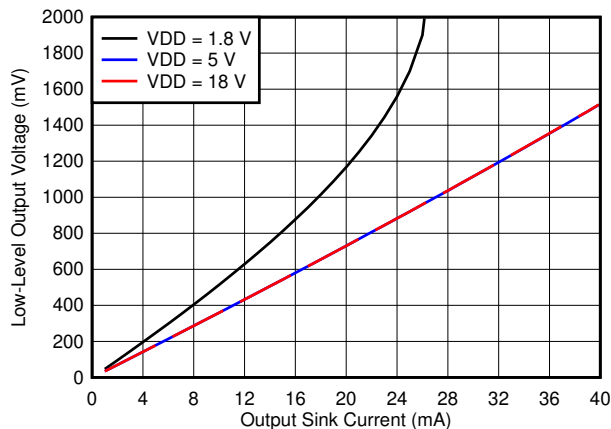


Figure 7-12. Output Voltage Low (V_{OL}) vs Output Sink Current (85°C)

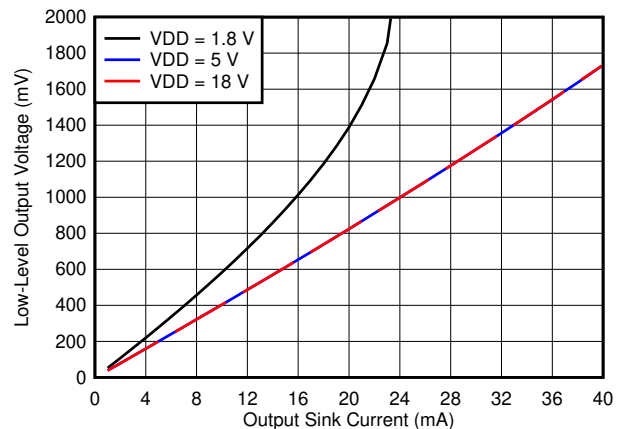


Figure 7-13. Output Voltage Low (V_{OL}) vs Output Sink Current (125°C)

8 Detailed Description

8.1 Overview

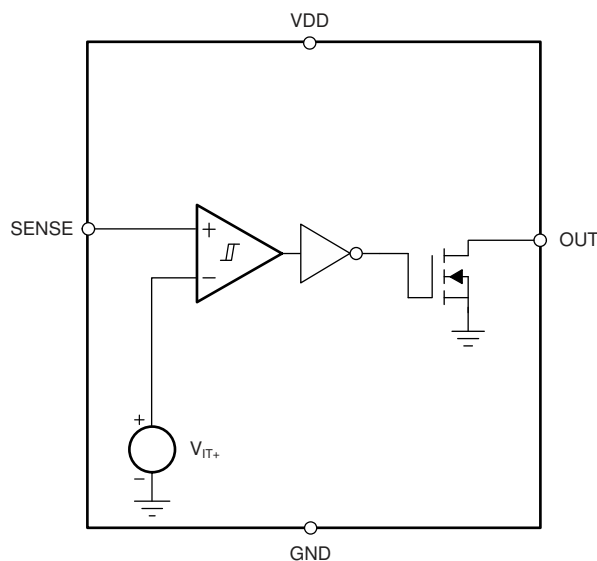
The TLV6703-Q1 provides precision voltage detection. The TLV6703-Q1 is a wide-supply voltage range (1.8 V to 18 V) comparator with a high-accuracy rising input threshold of 400 mV (1% over temperature) and built-in hysteresis. The output is also rated to 18 V, independent of supply voltage, and can sink up to 40 mA.

The TLV6703-Q1 asserts the output signal, as shown in [Table 8-1](#). To monitor any voltage above 0.4 V, set the input using an external resistor divider network. Each input pin has very low input leakage current, allowing the use of large resistor dividers without sacrificing system accuracy. Broad voltage thresholds are supported that enable the device for use in a wide array of applications.

Table 8-1. TLV6703-Q1 Truth Table

CONDITION	OUTPUT	OUTPUT STATE
$\text{SENSE} > V_{IT+}$	OUT high	Output high impedance
$\text{SENSE} < V_{IT-}$	OUT low	Output sinking

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Input Pin (SENSE)

The TLV6703-Q1 comparator has two inputs: one external input, and one input internally connected to the internal 400mV reference. The comparator rising threshold is trimmed to be equal to the reference voltage (400 mV). The comparator also has a built-in falling hysteresis that makes the device less sensitive to supply-rail noise and provides stable operation.

The comparator input (SENSE) is able to swing from ground to 6.5 V, regardless of the device supply voltage. Although not required in most cases, to reduce sensitivity to transients and layout parasitics for extremely noisy applications, place a 1-nF to 10-nF bypass capacitor at the comparator input.

OUT is driven to logic low when the input SENSE voltage drops below (V_{IT-}). When the voltage exceeds V_{IT+} , the output (OUT) goes to a high-impedance state; see [Figure 7-1](#).

8.3.2 Output Pin (OUT)

In a typical TLV6703-Q1 application, the output is connected to a GPIO input of the processor (such as a digital signal processor [DSP], central processing unit [CPU], field-programmable gate array [FPGA], or application-specific integrated circuit [ASIC]).

The TLV6703-Q1 device provides an open-drain output (OUT). Use a pullup resistor to hold this line high when the output goes to high impedance (not asserted). To connect the output to another device at the correct interface-voltage level, connect a pullup resistor to the proper voltage rail. The TLV6703-Q1 output can be pulled up to 18 V, independent of the device supply voltage.

[Table 8-1](#) and the [Section 8.3.1](#) section describe how the output is asserted or deasserted. See for a [Figure 7-1](#) timing diagram that describes the relationship between threshold voltage and the respective output.

8.3.3 Immunity to Input-Pin Voltage Transients

The TLV6703-Q1 is relatively immune to short voltage transient spikes on the sense pin. Sensitivity to transients depends on both transient duration and amplitude; see [Figure 7-7](#), *Minimum Pulse Width vs Threshold Overdrive Voltage*.

8.4 Device Functional Modes

8.4.1 Normal Operation ($V_{DD} > UVLO$)

When the voltage on V_{DD} is greater than 1.8 V for at least 150 μ s, the OUT signal correspond to the voltage on SENSE as listed in [Table 8-1](#).

8.4.2 Undervoltage Lockout ($V_{POR} < V_{DD} < UVLO$)

When the voltage on V_{DD} is less than the device UVLO voltage, and greater than the power-on reset voltage, V_{POR} , the OUT signal is asserted regardless of the voltage on SENSE.

8.4.3 Power-On Reset ($V_{DD} < V_{POR}$)

When the voltage on V_{DD} is lower than the required voltage to internally pull the asserted output to GND (V_{POR}), SENSE is in a high-impedance state.

9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TLV6703-Q1 device is a wide-supply voltage comparator that operates over a V_{DD} range of 1.8 V to 18 V. The device has a high-accuracy comparator with an internal 400-mV reference and an open-drain output rated to 18 V for precision voltage detection. The device can be used as a voltage monitor. The monitored voltage are set with the use of external resistors.

9.1.1 V_{PULLUP} to a Voltage Other Than V_{DD}

The output is often tied to V_{DD} through a resistor. However, some applications may require the output to be pulled up to a higher or lower voltage than V_{DD} to correctly interface with the reset and enable pins of other devices.

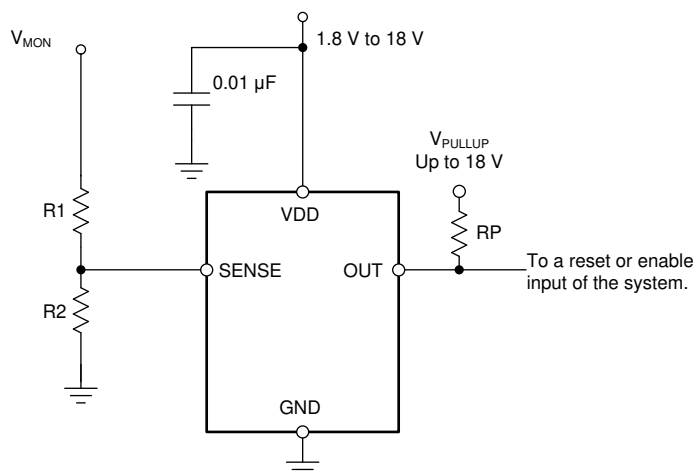


Figure 9-1. Interfacing to a Voltage Other Than V_{DD}

9.1.2 Monitoring V_{DD}

Many applications monitor the same rail that is powering V_{DD} . In these applications the resistor divider is simply connected to the V_{DD} rail.

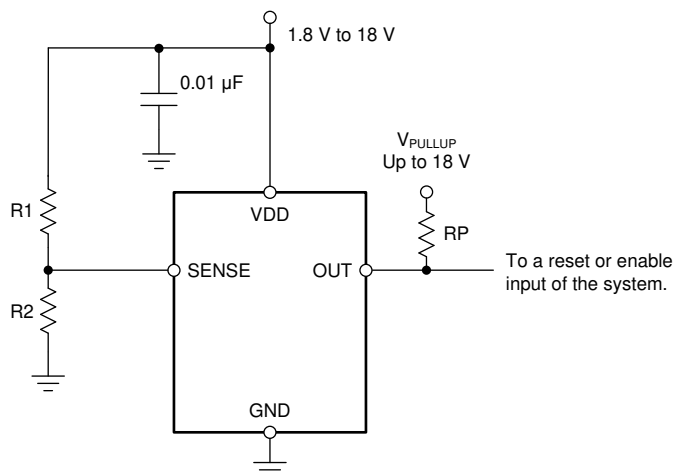
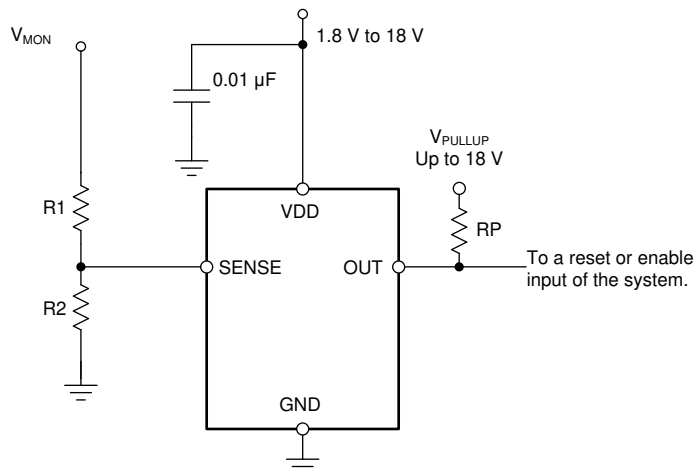


Figure 9-2. Monitoring the Same Voltage as V_{DD}

9.1.3 Monitoring a Voltage Other Than V_{DD}

Some applications monitor rails other than the one that is powering V_{DD} . In these types of applications the resistor divider used to set the desired threshold is connected to the rail that is being monitored.



NOTE: The input can monitor a voltage greater than maximum V_{DD} with the use of an external resistor divider network.

Figure 9-3. Monitoring a Voltage Other Than V_{DD}

9.2 Typical Application

The TLV6703-Q1 device is a wide-supply voltage comparator that operates over a V_{DD} range of 1.8 to 18 V. The monitored voltage is set with the use of external resistors, so the device can be used either as a precision voltage monitor.

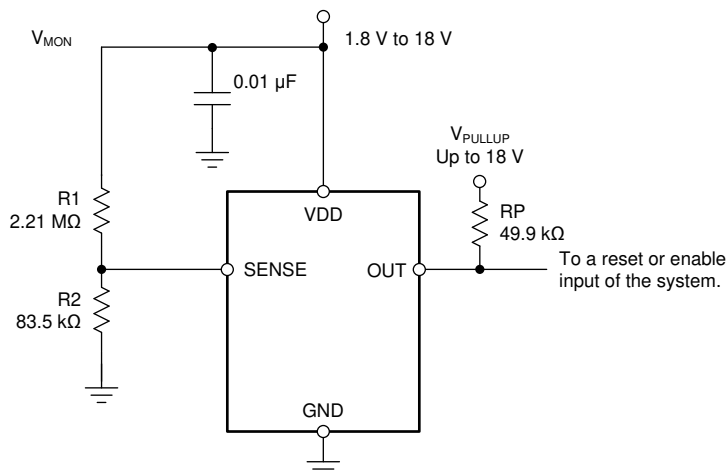


Figure 9-4. Wide VIN Voltage Monitor

9.2.1 Design Requirements

For this design example, use the values summarized in [Table 9-1](#) as the input parameters.

Table 9-1. Design Parameters

PARAMETER	DESIGN REQUIREMENT	DESIGN RESULT
Monitored voltage	12-V nominal rail with maximum falling threshold of 10%	$V_{MON(UV)} = 10.99 \text{ V}$ (8.33%)

9.2.2 Detailed Design Procedure

9.2.2.1 Resistor Divider Selection

The resistor divider values and target threshold voltage can be calculated by using [Equation 1](#) to determine $V_{MON(UV)}$.

$$V_{MON(UV)} = \left(1 + \frac{R1}{R2} \right) \times V_{IT-} \quad (1)$$

where

- R1 and R2 are the resistor values for the resistor divider on the SENSEx pins
- $V_{MON(UV)}$ is the target voltage at which an undervoltage condition is detected

Choose R_{TOTAL} ($= R1 + R2$) so that the current through the divider is approximately 100 times higher than the input current at the SENSE pin. The resistors can have high values to minimize current consumption as a result of low input bias current without adding significant error to the resistive divider. For details on sizing input resistors, refer to application report [SLVA450, Optimizing Resistor Dividers at a Comparator Input](#), available for download from www.ti.com.

9.2.2.2 Pullup Resistor Selection

To ensure the proper voltage level, the pullup resistor value is selected by ensuring that the pullup voltage divided by the resistor does not exceed the sink-current capability of the device. This confirmation is calculated by verifying that the pullup voltage minus the output-leakage current ($I_{lk(OD)}$) multiplied by the resistor is greater than the desired logic-high voltage. These values are specified in the [Section 7.5](#).

Use [Equation 2](#) to calculate the value of the pullup resistor.

$$\frac{(V_{HI} - V_{PU})}{I_{lk(OD)}} \geq R_{PU} \geq \frac{V_{PU}}{I_O} \quad (3)$$

9.2.2.3 Input Supply Capacitor

Although an input capacitor is not required for stability, for good analog design practice, connect a 0.1-μF low equivalent series resistance (ESR) capacitor across the VDD and GND pins. A higher-value capacitor may be necessary if large, fast rise-time load transients are anticipated, or if the device is not located close to the power source.

9.2.2.4 Sense Capacitor

Although not required in most cases, for extremely noisy applications, place a 1-nF to 10-nF bypass capacitor from the comparator input (SENSE) to the GND pin for good analog design practice. This capacitor placement reduces device sensitivity to transients.

9.2.3 Application Curves

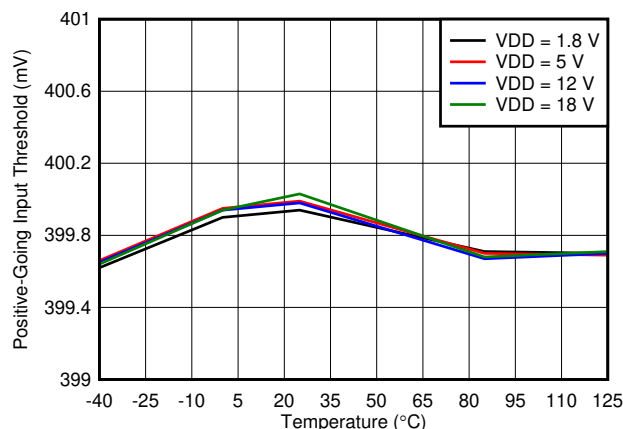


Figure 9-5. Rising Input Threshold Voltage (V_{IT+}) vs Temperature

9.3 Dos and Don'ts

Do connect a 0.1-μF decoupling capacitor from V_{DD} to GND for best system performance.

If the monitored rail is noisy, do connect a decoupling capacitor from the comparator input (sense) to GND.

Don't use resistors for the voltage divider that cause the current through them to be less than 100 times the input current of the comparator without also accounting for the effect to the accuracy.

Don't use a pullup resistor that is too small, because the larger current sunk by the output then exceeds the desired low-level output voltage (V_{OL}).

10 Power-Supply Recommendations

These devices operate from an input voltage supply range between 1.8 V and 18 V.

11 Layout

11.1 Layout Guidelines

Placing a 0.1- μ F capacitor close to the VDD pin to reduce the input impedance to the device is good analog design practice.

11.2 Layout Example

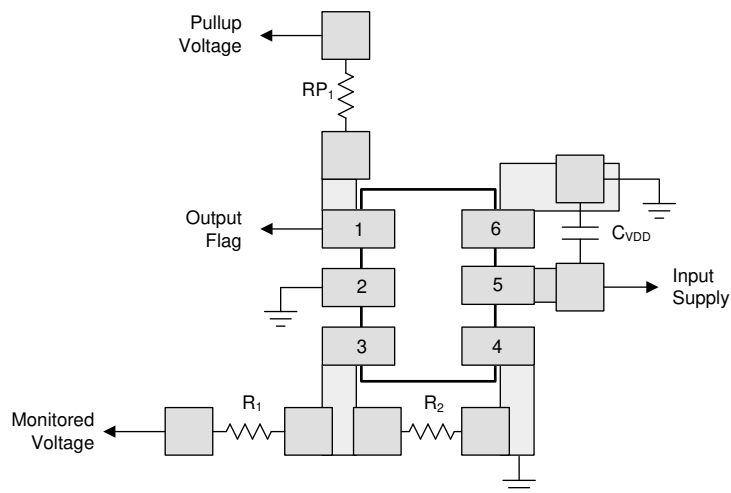


Figure 11-1. Layout Example

12 Device and Documentation Support

12.1 Device Support

12.1.1 Development Support

The [DIP Adapter Evaluation Module](#) allows conversion of the SOT-23-6 package to a standard DIP-6 pinout for ease of prototyping and bench evaluation.

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

12.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV6703QDSERQ1	Active	Production	WSO (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	K7
TLV6703QDSERQ1.B	Active	Production	WSO (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	K7

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

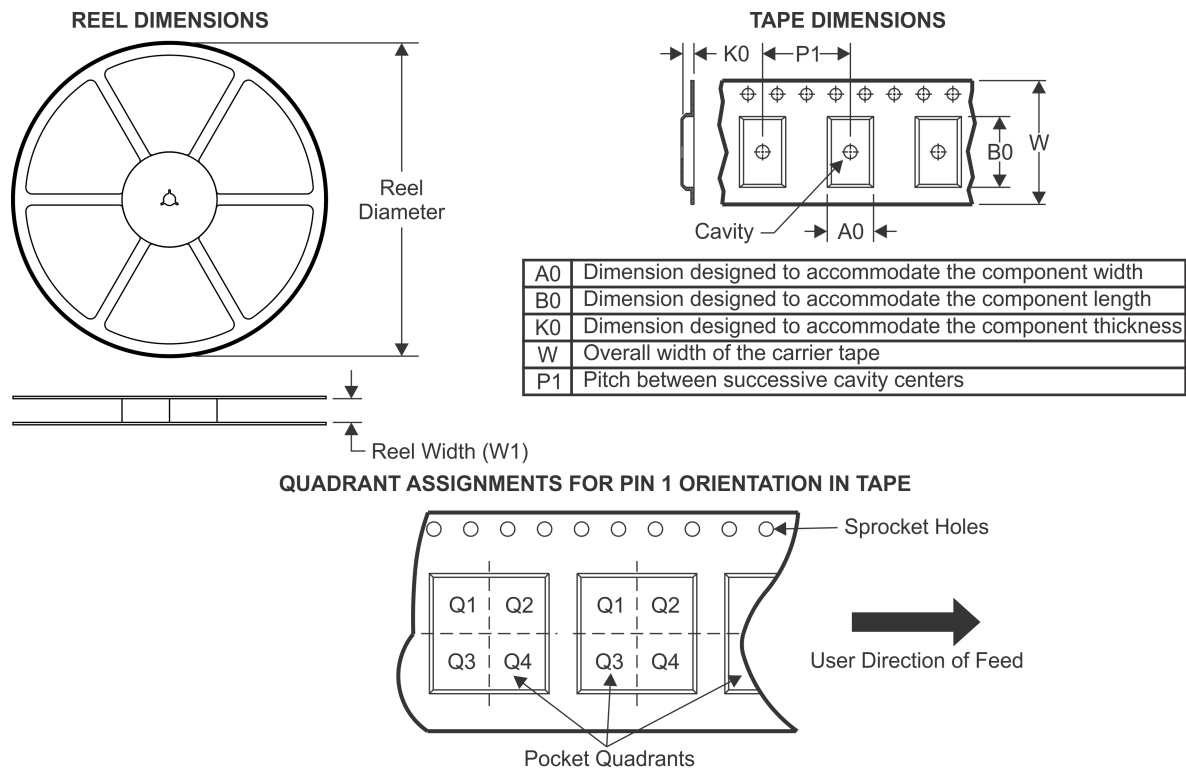
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TLV6703-Q1 :

- Catalog : [TLV6703](#)

NOTE: Qualified Version Definitions:

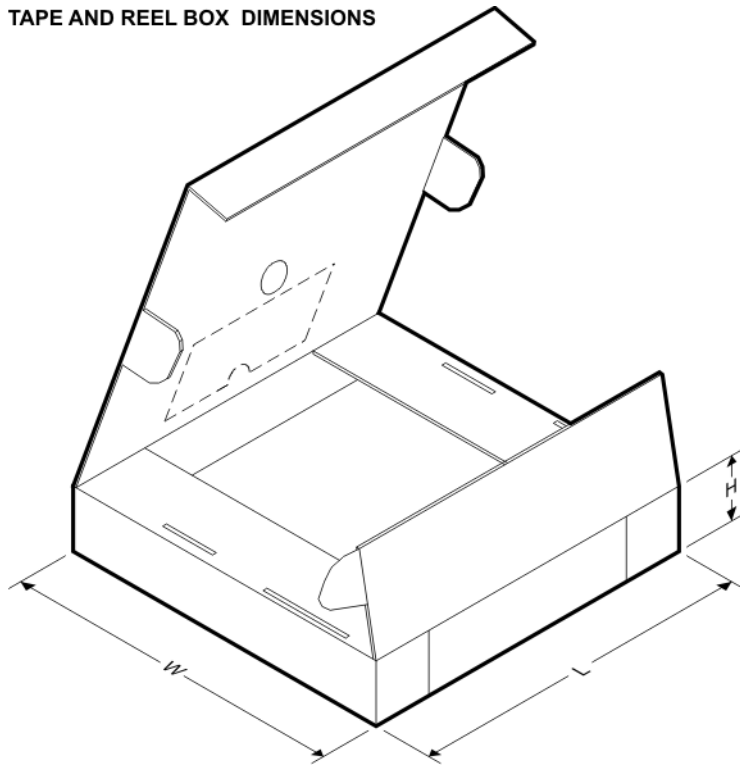
- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION


*All dimensions are nominal

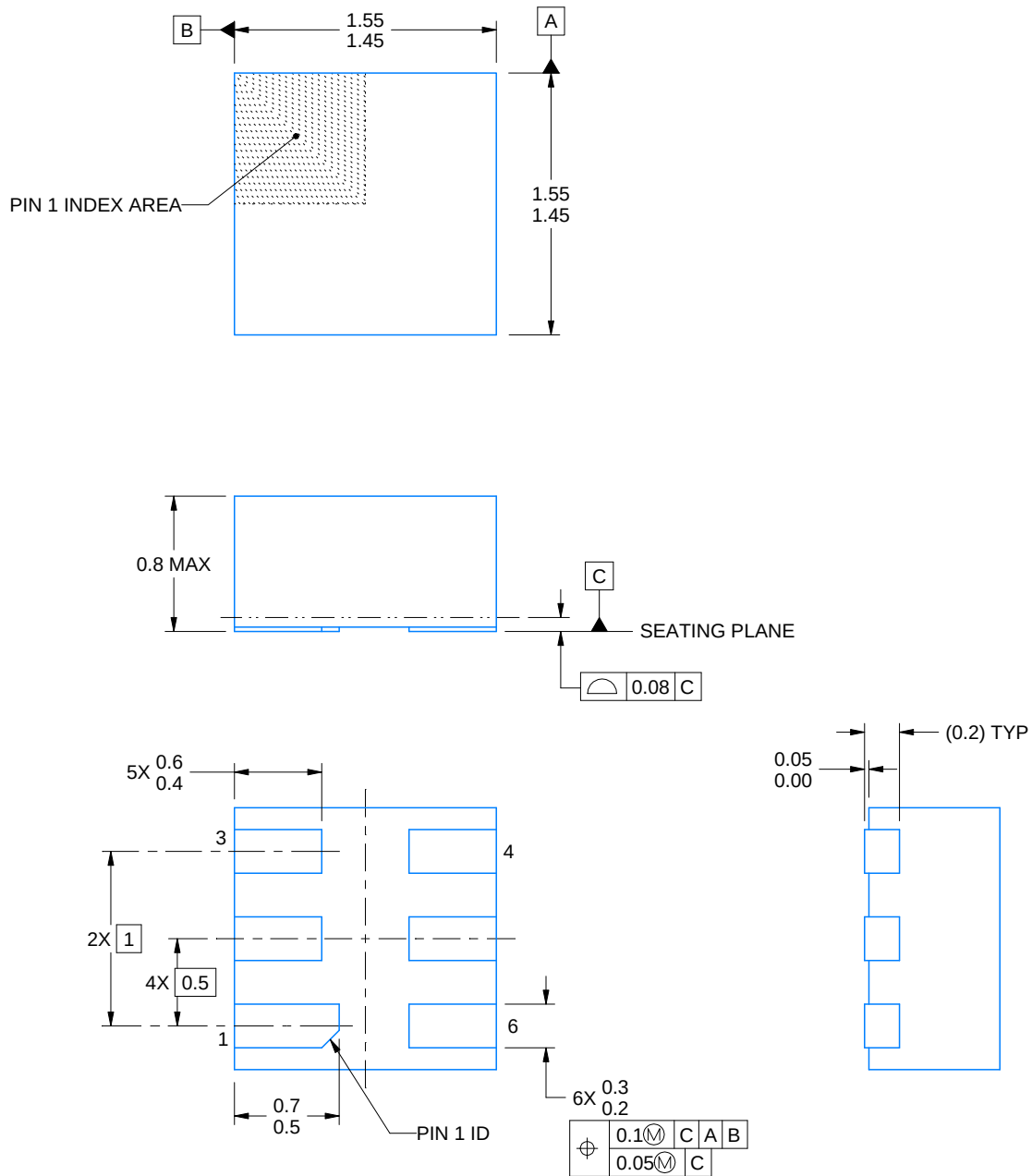
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV6703QDSERQ1	WSO	DSE	6	3000	180.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV6703QDSERQ1	WS0N	DSE	6	3000	213.0	191.0	35.0



4220552/B 01/2024

NOTES:

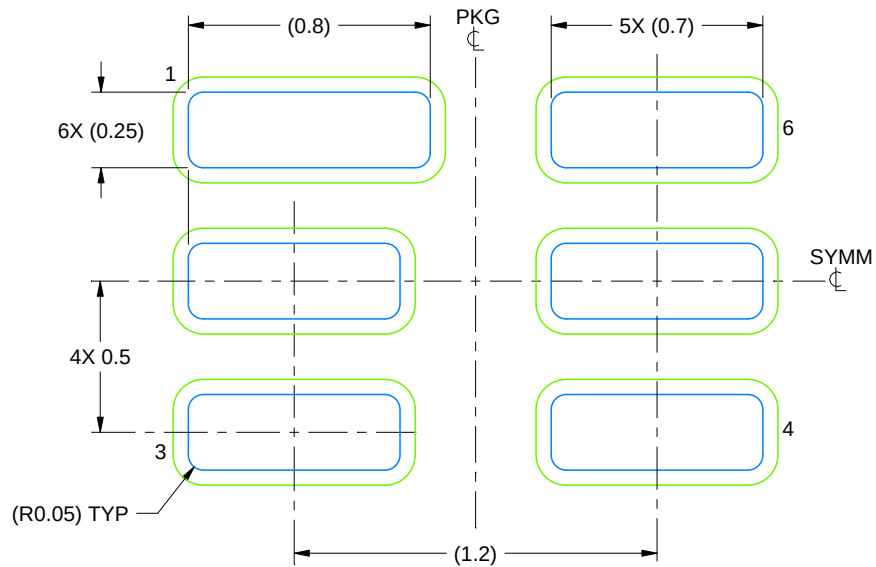
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

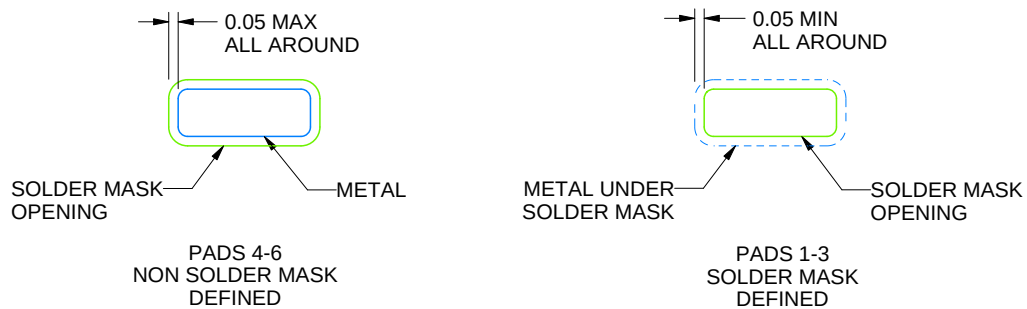
DSE0006A

WSN - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
SCALE:40X



SOLDER MASK DETAILS

4220552/B 01/2024

NOTES: (continued)

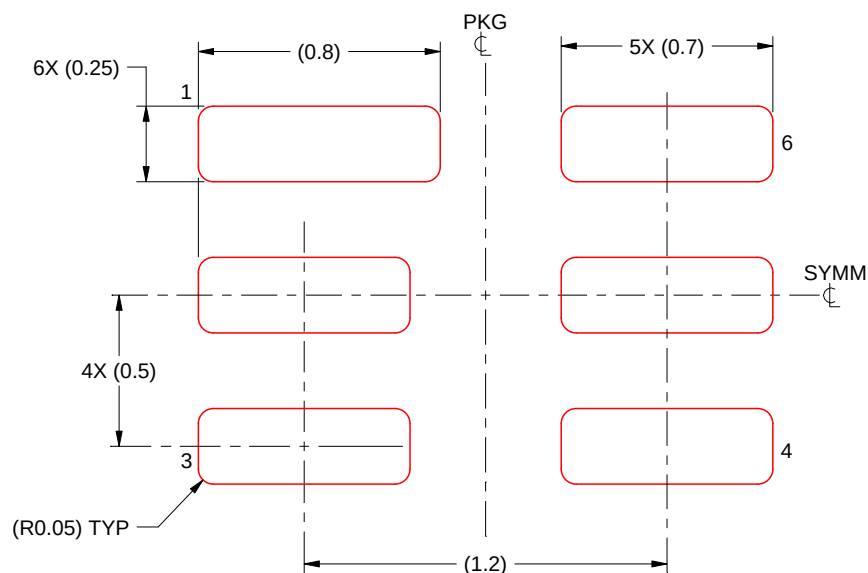
3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

EXAMPLE STENCIL DESIGN

DSE0006A

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:40X

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](#) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2025, Texas Instruments Incorporated